MOTOROLA

SN54/74LS132

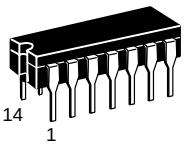
QUAD 2-INPUT SCHMITT TRIGGER NAND GATE

The SN54/74LS132 contains four 2-Input NAND Gates which accept standard TTL input signals and provide standard TTL output levels. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. Additionally, they have greater noise margin than conventional NAND Gates.

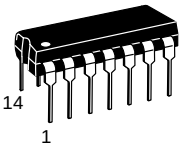
Each circuit contains a 2-input Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input thresholds (typically 800 mV) is determined internally by resistor ratios and is essentially insensitive to temperature and supply voltage variations. As long as one input remains at a more positive voltage than V_{T+} (MAX), the gate will respond to the transitions of the other input as shown in Figure 1.

QUAD 2-INPUT
SCHMITT TRIGGER NAND GATE

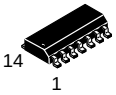
LOW POWER SCHOTTKY



J SUFFIX
CERAMIC
CASE 632-08



N SUFFIX
PLASTIC
CASE 646-06

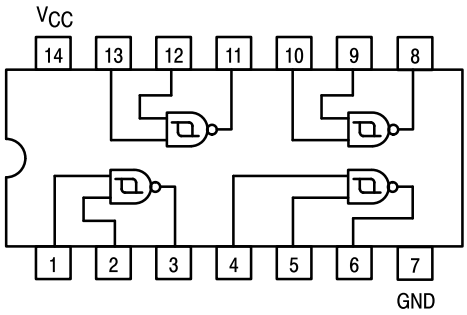


D SUFFIX
SOIC
CASE 751A-02

ORDERING INFORMATION

SN54LSXXXJ	Ceramic
SN74LSXXXN	Plastic
SN74LSXXXD	SOIC

LOGIC AND CONNECTION DIAGRAM
DIP (TOP VIEW)



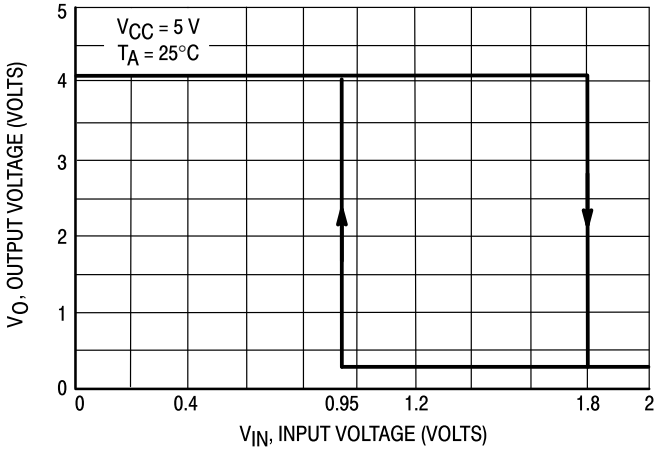


Figure 1. V_{IN} versus V_{OUT} Transfer Function

GUARANTEED OPERATING RANGES

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	54 74	4.5 4.75	5.0 5.0	5.5 5.25	V
T_A	Operating Ambient Temperature Range	54 74	–55 0	25 25	125 70	°C
I_{OH}	Output Current — High	54, 74			–0.4	mA
I_{OL}	Output Current — Low	54 74			4.0 8.0	mA

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter		Limits Min	Limits Typ	Limits Max	Unit	Test Conditions
V_{T+}	Positive-Going Threshold Voltage		1.5		2.0	V	V_{CC} = 5.0 V
V_{T-}	Negative-Going Threshold Voltage		0.6		1.1	V	V_{CC} = 5.0 V
$V_{T+} - V_{T-}$	Hysteresis		0.4	0.8		V	V_{CC} = 5.0 V
V_{IK}	Input Clamp Diode Voltage			–0.65	–1.5	V	V_{CC} = MIN, I_{IN} = –18 mA
V_{OH}	Output HIGH Voltage	54	2.5	3.4		V	V_{CC} = MIN, I_{OH} = –400 µA, V_{IN} = V_{IL}
		74	2.7	3.4			
V_{OL}	Output LOW Voltage	54, 74		0.25	0.4	V	V_{CC} = MIN, I_{OL} = 4.0 mA, V_{IN} = 2.0 V
		74		0.35	0.5	V	V_{CC} = MIN, I_{OL} = 8.0 mA, V_{IN} = 2.0 V
I_{T+}	Input Current at Positive-Going Threshold			–0.14		mA	V_{CC} = 5.0 V, V_{IN} = V_{T+}
I_{T-}	Input Current at Negative-Going Threshold			–0.18		mA	V_{CC} = 5.0 V, V_{IN} = V_{T-}
I_{IH}	Input HIGH Current				20	µA	V_{CC} = MAX, V_{IN} = 2.7 V
					0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V
I_{IL}	Input LOW Current				–0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V
I_{OS}	Output Short Circuit Current (Note 1)		–20		–100	mA	V_{CC} = MAX, V_{OUT} = 0 V
I_{CC}	Power Supply Current Total, Output HIGH			5.9	11	mA	V_{CC} = MAX, V_{IN} = 0 V
	Total, Output LOW			8.2	14	mA	V_{CC} = MAX, V_{IN} = 4.5 V

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C)

Symbol	Parameter	Limits Min	Limits Typ	Limits Max	Unit	Test Conditions
t_{PLH}	Turn-Off Delay, Input to Output			22	ns	V_{CC} = 5.0 V C_L = 15 pF
t_{PHL}	Turn-On Delay, Input to Output			22	ns	

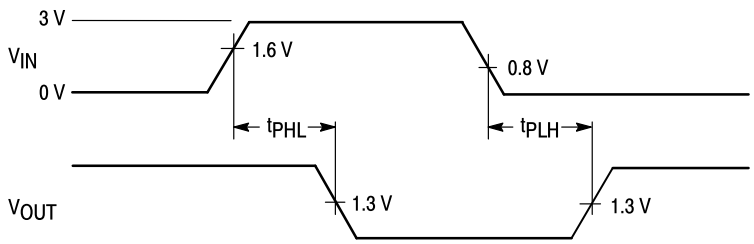


Figure 2. AC Waveforms

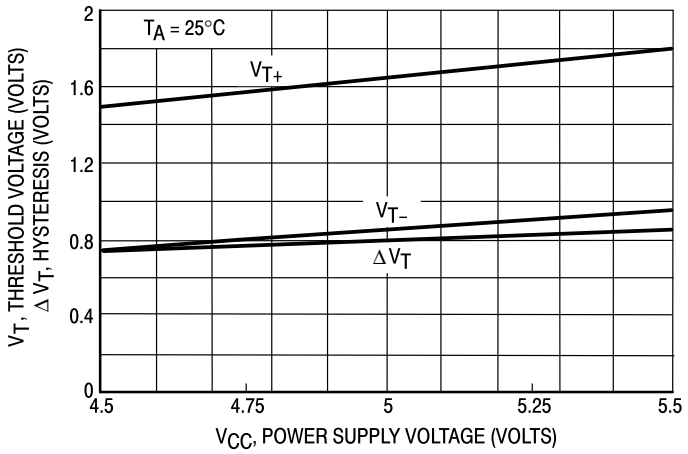


Figure 3. Threshold Voltage and Hysteresis versus Power Supply Voltage

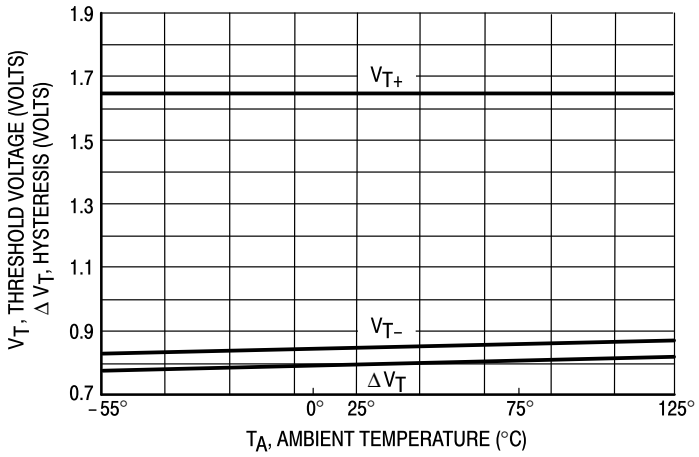
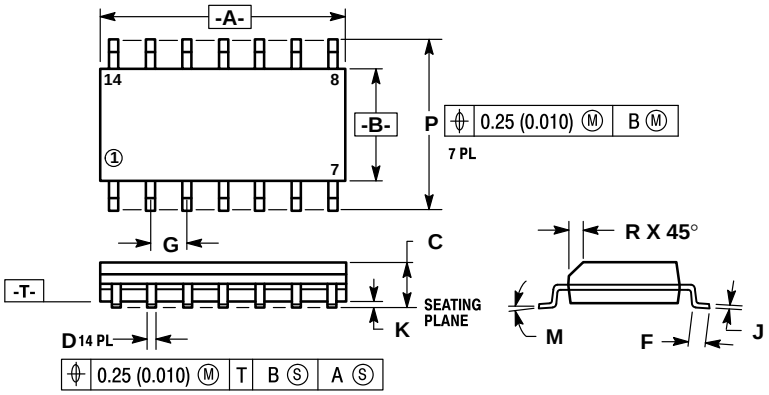


Figure 4. Threshold Voltage and Hysteresis versus Temperature

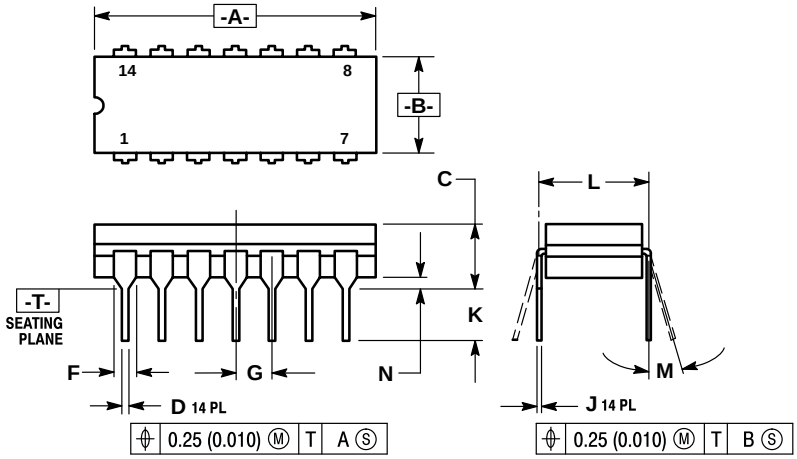
Case 751A-02 D Suffix
14-Pin Plastic
SO-14



NOTES:
1. DIMENSIONS "A" AND "B" ARE DATUMS AND "T" IS A DATUM SURFACE.
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
3. CONTROLLING DIMENSION: MILLIMETER.
4. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
5. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
6. 751A-01 IS OBSOLETE, NEW STANDARD 751A-02.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

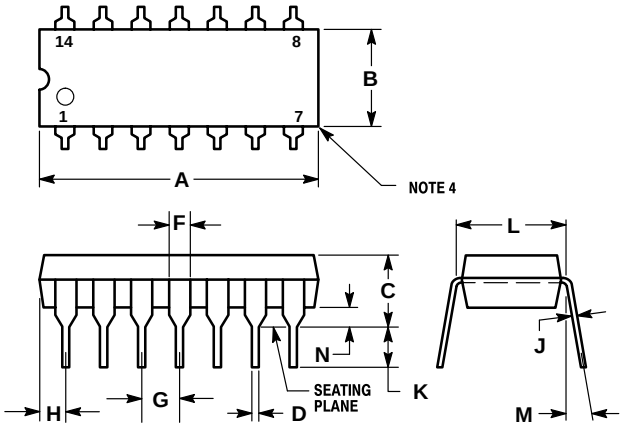
Case 632-08 J Suffix
14-Pin Ceramic Dual In-Line



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIM F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.
5. 632-01 THRU -07 OBSOLETE, NEW STANDARD 632-08.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	19.05	19.94	0.750	0.785
B	6.23	7.11	0.245	0.280
C	3.94	5.08	0.155	0.200
D	0.39	0.50	0.015	0.020
F	1.40	1.65	0.055	0.065
G	2.54 BSC		0.100 BSC	
J	0.21	0.38	0.008	0.015
K	3.18	4.31	0.125	0.170
L	7.62 BSC		0.300 BSC	
M	0°	15°	0°	15°
N	0.51	1.01	0.020	0.040

Case 646-06 N Suffix
14-Pin Plastic



NOTES:
1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
2. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
4. ROUNDED CORNERS OPTIONAL.
5. 646-05 OBSOLETE, NEW STANDARD 646-06.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	18.16	19.56	0.715	0.770
B	6.10	6.60	0.240	0.260
C	3.69	4.69	0.145	0.185
D	0.38	0.53	0.015	0.021
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	1.32	2.41	0.052	0.095
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	0°	10°	0°	10°
N	0.39	1.01	0.015	0.039

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